NSN 5961-01-211-8874

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View Online at https://aerobasegroup.com/nsn/5961-01-211-8874 **Inclosure Material:** Metal **Overall Length:** Between 0.970 inches and 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-111 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.428 inches and 0.438 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** -5.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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